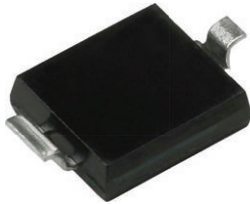


## Silicon PIN Photodiode



VBP104FAS



VBP104FASR

### FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 6.4 x 3.9 x 1.2
- Radiant sensitive area (in mm<sup>2</sup>): 4.4
- High radiant sensitivity
- Daylight blocking filter matched with 870 nm to 950 nm emitters
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 65^\circ$
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### DESCRIPTION

VBP104FAS and VBP104FASR are high speed and high sensitive PIN photodiodes. It is a surface mount device (SMD) including the chip with a 4.4 mm<sup>2</sup> sensitive area and a daylight blocking filter matched with IR emitters operating at wavelength 870 nm or 950 nm.

### APPLICATIONS

- High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

### PRODUCT SUMMARY

| COMPONENT  | $I_{ra}$ ( $\mu A$ ) | $\phi$ (deg) | $\lambda_{0.5}$ (nm) |
|------------|----------------------|--------------|----------------------|
| VBP104FAS  | 35                   | $\pm 65$     | 780 to 1050          |
| VBP104FASR | 35                   | $\pm 65$     | 780 to 1050          |

#### Note

- Test conditions see table "Basic Characteristics"

### ORDERING INFORMATION

| ORDERING CODE | PACKAGING     | REMARKS                      | PACKAGE FORM     |
|---------------|---------------|------------------------------|------------------|
| VBP104FAS     | Tape and reel | MOQ: 1000 pcs, 1000 pcs/reel | Gullwing         |
| VBP104FASR    | Tape and reel | MOQ: 1000 pcs, 1000 pcs/reel | Reverse gullwing |

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ C$ , unless otherwise specified)

| PARAMETER                           | TEST CONDITION                    | SYMBOL     | VALUE       | UNIT       |
|-------------------------------------|-----------------------------------|------------|-------------|------------|
| Reverse voltage                     |                                   | $V_R$      | 60          | V          |
| Power dissipation                   | $T_{amb} \leq 25^\circ C$         | $P_V$      | 215         | mW         |
| Junction temperature                |                                   | $T_j$      | 100         | $^\circ C$ |
| Operating temperature range         |                                   | $T_{amb}$  | -40 to +100 | $^\circ C$ |
| Storage temperature range           |                                   | $T_{stg}$  | -40 to +100 | $^\circ C$ |
| Soldering temperature               | Acc. reflow solder profile fig. 8 | $T_{sd}$   | 260         | $^\circ C$ |
| Thermal resistance junction/ambient |                                   | $R_{thJA}$ | 350         | K/W        |



| BASIC CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |  |                 |      |                     |      |                             |
|--|--|-----------------|------|---------------------|------|-----------------------------|
| PARAMETER  | TEST CONDITION   | SYMBOL          | MIN. | TYP.                | MAX. | UNIT                        |
| Forward voltage  | $I_F = 50\text{ mA}$   | $V_F$           |      | 1                   | 1.3  | V                           |
| Breakdown voltage  | $I_R = 100\text{ }\mu\text{A}$ , $E = 0$                                   | $V_{(BR)}$      | 60   |                     |      | V                           |
| Reverse dark current   | $V_R = 10\text{ V}$ , $E = 0$  | $I_{ro}$        |      | 2                   | 30   | nA                          |
| Diode capacitance  | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$                          | $C_D$           |      | 48                  |      | pF                          |
|  | $V_R = 3\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$                          | $C_D$           |      | 17                  | 40   | pF                          |
| Open circuit voltage   | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                       | $V_o$           |      | 350                 |      | mV                          |
| Temperature coefficient of $V_o$   | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                       | $TK_{V_o}$      |      | -2.6                |      | mV/K                        |
| Short circuit current  | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                       | $I_k$           |      | 32                  |      | $\mu\text{A}$               |
| Temperature coefficient of $I_k$   | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                       | $TK_{I_k}$      |      | 0.1                 |      | %/K                         |
| Reverse light current  | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$ , $V_R = 5\text{ V}$  | $I_{ra}$        | 25   | 35                  |      | $\mu\text{A}$               |
| Angle of half sensitivity  |  | $\phi$          |      | $\pm 65$            |      | deg                         |
| Wavelength of peak sensitivity   |  | $\lambda_p$     |      | 950                 |      | nm                          |
| Range of spectral bandwidth  |  | $\lambda_{0.5}$ |      | 780 to 1050         |      | nm                          |
| Noise equivalent power   | $V_R = 10\text{ V}$ , $\lambda = 950\text{ nm}$                            | NEP             |      | $4 \times 10^{-14}$ |      | $\text{W}/\sqrt{\text{Hz}}$ |
| Rise time  | $V_R = 10\text{ V}$ , $R_L = 1\text{ k}\Omega$ , $\lambda = 820\text{ nm}$ | $t_r$           |      | 100                 |      | ns                          |
| Fall time  | $V_R = 10\text{ V}$ , $R_L = 1\text{ k}\Omega$ , $\lambda = 820\text{ nm}$ | $t_f$           |      | 100                 |      | ns                          |

**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

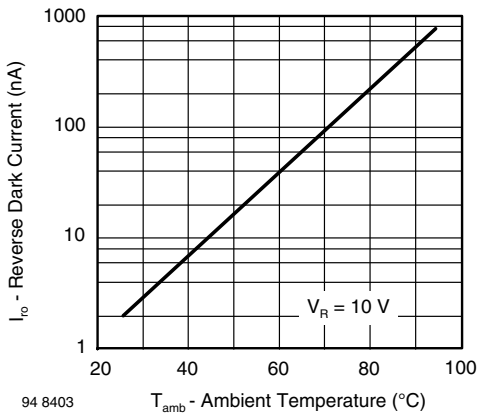


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

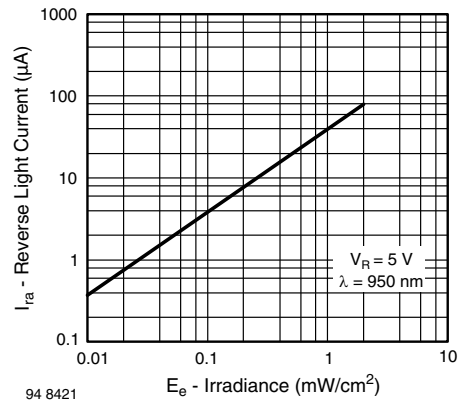


Fig. 3 - Reverse Light Current vs. Irradiance

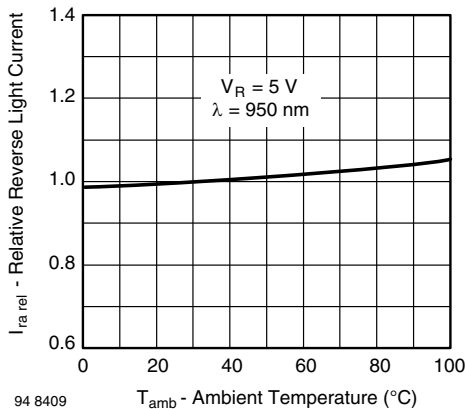


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

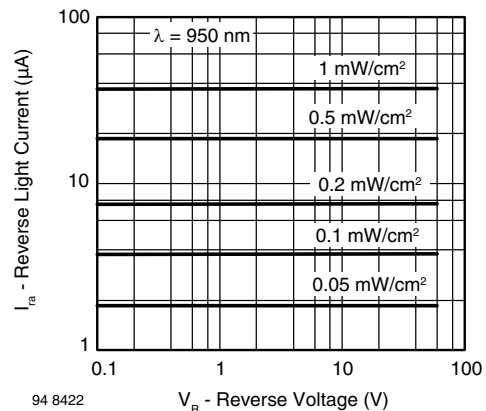


Fig. 4 - Reverse Light Current vs. Reverse Voltage

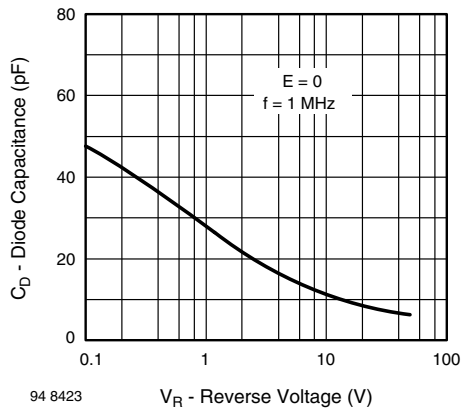


Fig. 5 - Diode Capacitance vs. Reverse Voltage

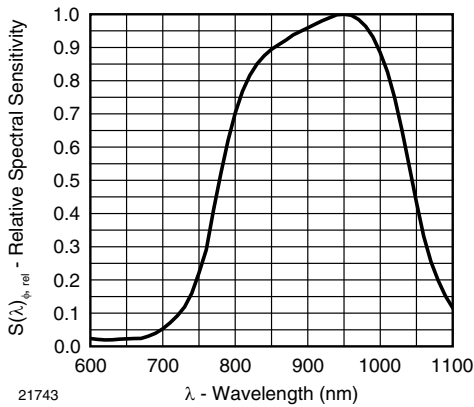


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

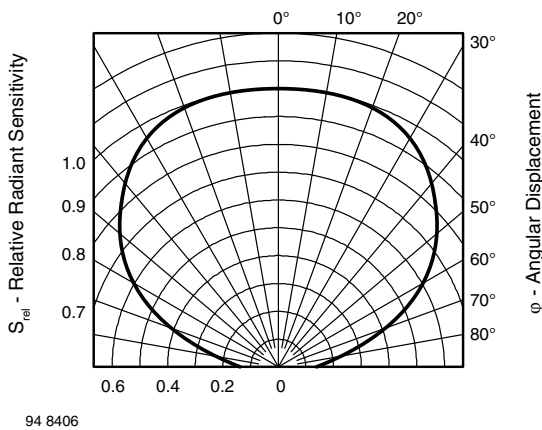
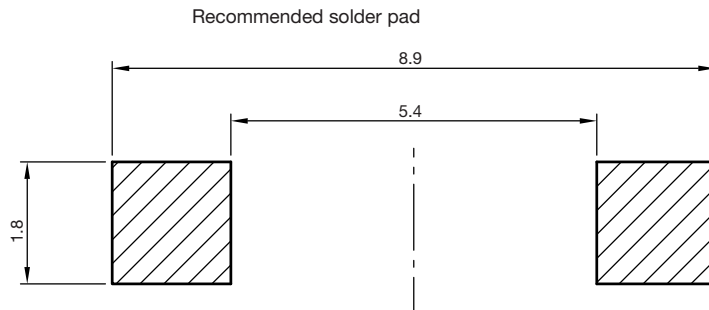
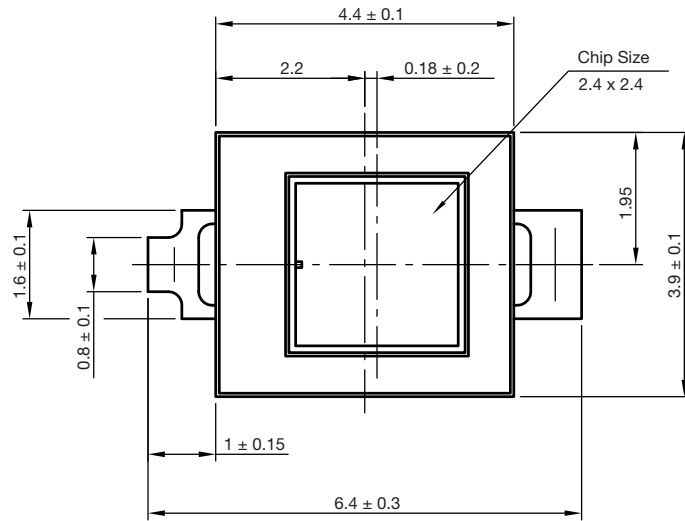
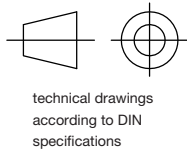
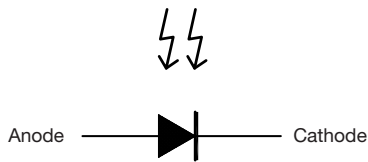
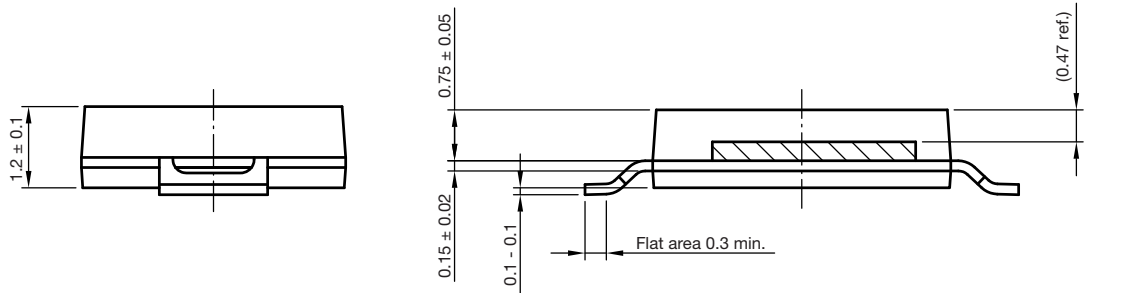


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement



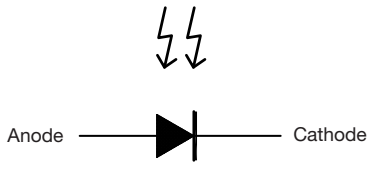
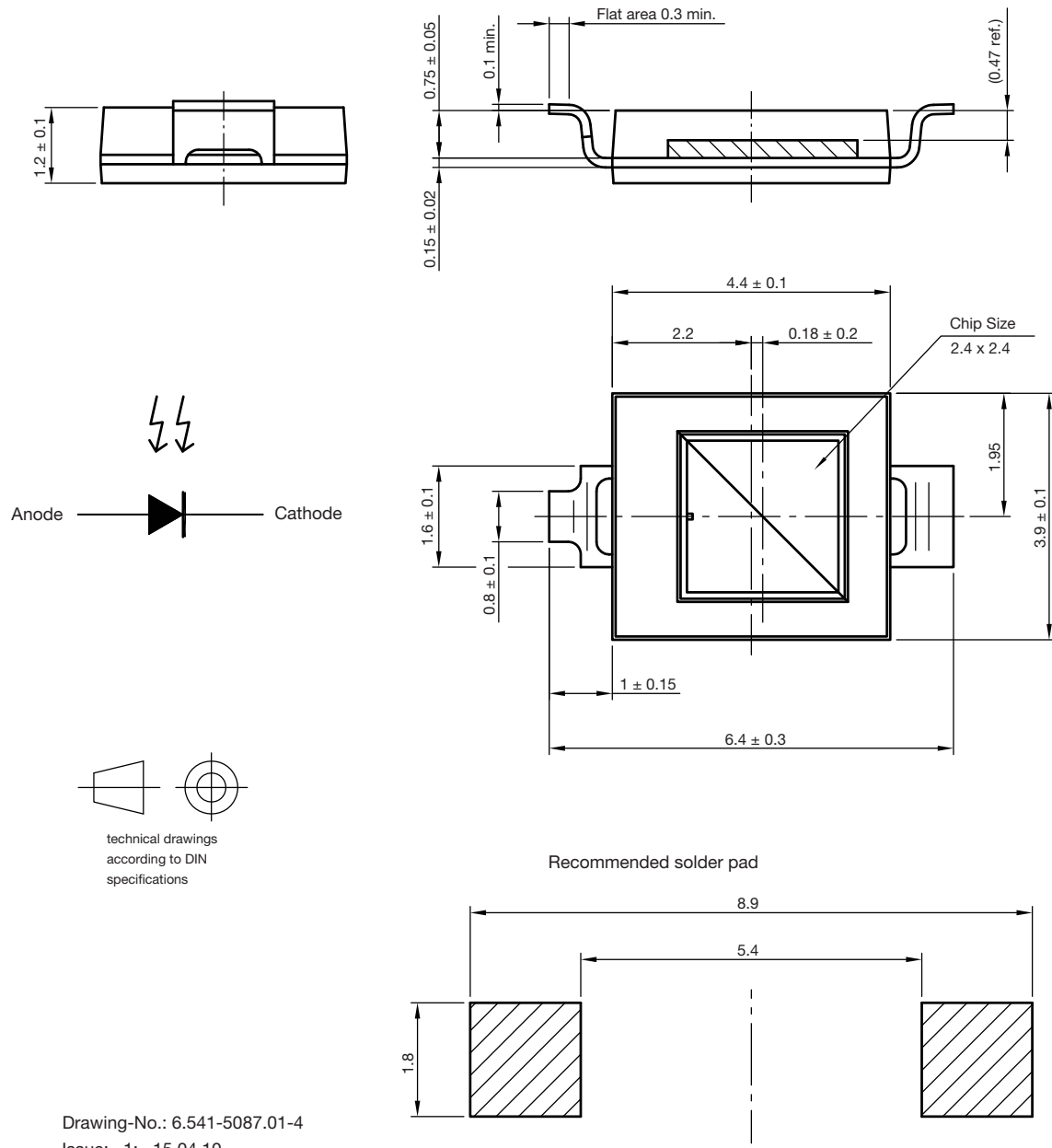
## PACKAGE DIMENSIONS FOR VBP104FAS in millimeters



Drawing-No.: 6.541-5088.01-4  
 Issue: 1; 15.04.10  
 22107



## PACKAGE DIMENSIONS FOR VBP104FASR in millimeters

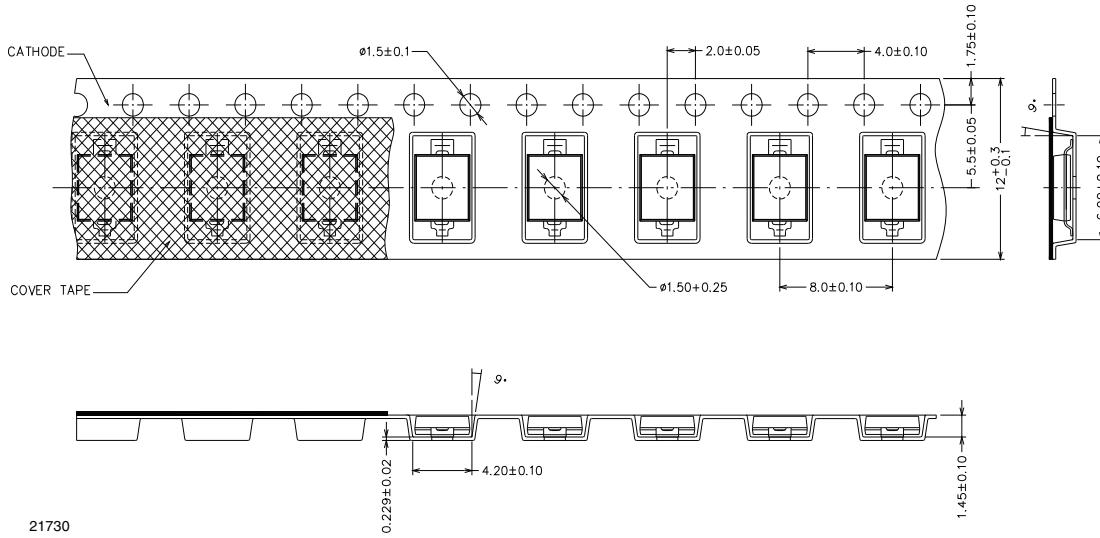


technical drawings according to DIN specifications

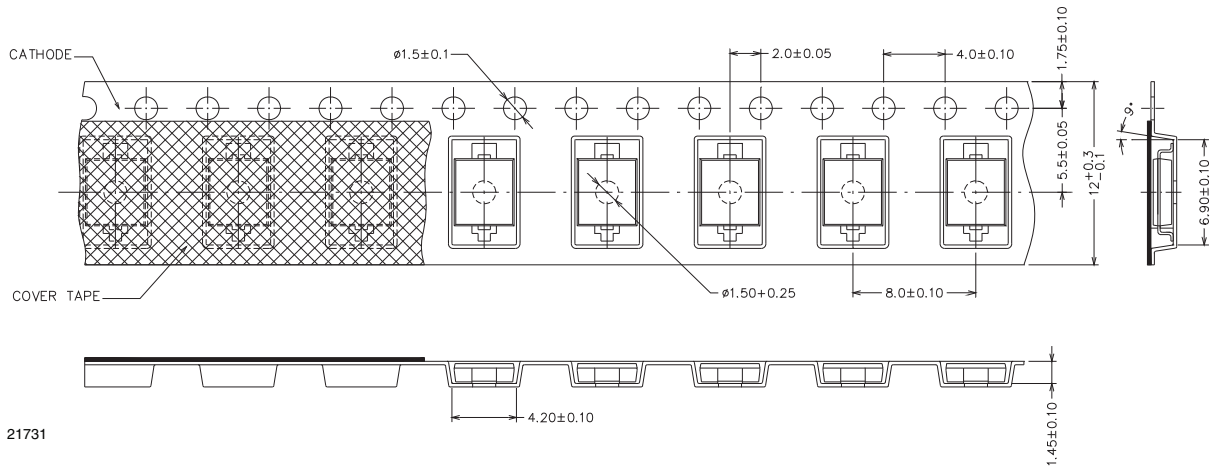
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 Issue: 1; 15.04.10  
 22106



### TAPING DIMENSIONS FOR VBP104FAS in millimeters

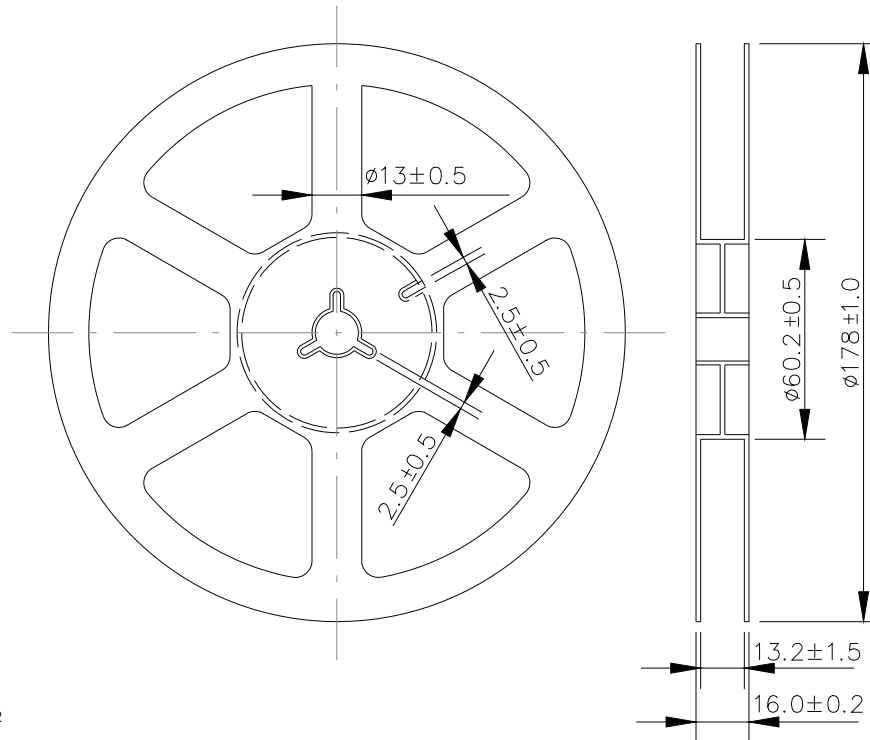


### TAPING DIMENSIONS FOR VBP104FASR in millimeters



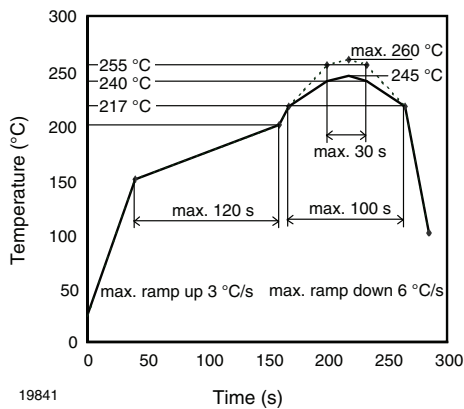


## REEL DIMENSIONS FOR VBP104FAS AND VBP104FASR in millimeters



21732

### SOLDER PROFILE



19841

Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

Conditions:  $T_{amb} < 30 \text{ }^\circ\text{C}$ ,  $RH < 60 \%$

### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C),  $RH < 5 \%$

or

96 h at 60 °C (+ 5 °C),  $RH < 5 \%$ .



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